

# Interfacial Electron-Phonon Coupling Constants Extracted from Intrinsic Replica Bands in Monolayer FeSe/SrTiO<sub>3</sub>

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The observation of replica bands by angle-resolved photoemission spectroscopy has ignited interest in the study of electron-phonon coupling at low carrier densities, particularly in monolayer FeSe/SrTiO<sub>3</sub>, where the appearance of replica bands has motivated theoretical work suggesting that the interfacial coupling of electrons in the FeSe layer to optical phonons in the SrTiO<sub>3</sub> substrate might contribute to the enhanced superconducting pairing temperature. Alternatively, it has also been recently proposed that such replica bands might instead originate from extrinsic final state losses associated with the photoemission process. Here, we perform a quantitative examination of replica bands in monolayer FeSe/SrTiO<sub>3</sub>, where we are able to conclusively demonstrate that the replica bands are indeed signatures of intrinsic electron-boson coupling, and not associated with final state effects. A detailed analysis of the energy splittings and relative peak intensities between the higher-order replicas, as well as other self-energy effects, allows us to determine that the interfacial electron-phonon coupling in the system corresponds to a value of  $\lambda = 0.19 \pm 0.02$ , providing valuable insights into the enhancement of superconductivity in monolayer FeSe/SrTiO<sub>3</sub>. The methodology employed here can also serve as a new and general approach for making more rigorous and quantitative comparisons to theoretical calculations of electron-phonon interactions and coupling constants.

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One of the most powerful attributes of angle-resolved photoemission spectroscopy (ARPES) is its ability to reveal many-body interactions through its line shape, owing to its close relationship to the single-particle spectral function  $A(\mathbf{k}, \omega)$ . ARPES has revealed the presence of strong electron-boson coupling in a variety of quantum materials, including high-temperature cuprate superconductors [1,2], colossal magnetoresistive manganites [3], and titanates [4]. At high carrier densities, electron-boson coupling is manifested as an abrupt kink in the quasiparticle dispersion occurring at the boson energy. At low carrier densities, where screening is weaker and the Fermi energy,  $E_F$ , can be comparable to the relevant phonon frequency,  $\Omega_0$ , the electron-phonon coupling can give rise to polaronic quasiparticles and the presence of satellite “replica bands,” which occur at near-integer multiples of  $\Omega_0$ . Such features have been recently reported in a variety of systems, including at the surface of SrTiO<sub>3</sub> [4–6], anatase TiO<sub>2</sub> [7,8], and most notably in monolayer FeSe films grown on SrTiO<sub>3</sub> [9–12], where it has been argued that the interfacial coupling of electrons in the FeSe monolayer to optical phonons in the SrTiO<sub>3</sub> substrate could potentially be responsible for its enhanced superconducting properties

[9]. On the other hand, it has also been recently suggested that these replica bands observed by ARPES are not signatures of intrinsic electron-phonon interactions, but rather could arise from extrinsic electron energy losses in the photoemission process, whereby ejected photoelectrons lose energy to surface phonons [13]. Such extrinsic “final-state effects” produced by photoelectron energy loss processes would appear very similar to intrinsic satellites. Further complicating the situation, such loss features should be prevalent in systems where the carrier density is low and screening effects are weak, precisely where polaronic quasiparticles and intrinsic replica bands in ARPES would also be expected.

Therefore, a detailed investigation of photoemission replica bands is imperative to distinguish whether they are indeed intrinsic features in the spectral function of quantum materials versus extrinsic final-state loss effects. Given the importance of ARPES as the premier tool for investigating electronic many-body interactions, this is critical not only for the understanding of ARPES as a technique, but also for the general study of quantum materials and many-body interactions. Furthermore, a more rigorous analysis of the experimental replica bands,

including their intensities and energy separations, can help to inform and constrain theoretical models which tackle the long-standing problem of electron-lattice interactions in quantum materials. To achieve this, we investigate molecular beam epitaxy (MBE)-grown, single layer FeSe/SrTiO<sub>3</sub> thin films, where such replica bands have been observed, but also where it has been suggested as potentially arising from extrinsic loss effects from Fuchs-Kliwer phonons in the SrTiO<sub>3</sub> substrate [14]. By employing a wide range of photon energies, we are able to conclusively determine that the replica bands indeed arise from intrinsic electron-phonon coupling between the FeSe film and SrTiO<sub>3</sub> substrate, and not from extrinsic losses. A quantitative analysis of the spectra in comparison to prior theoretical calculations also allows us to determine the coupling constant,  $\lambda = 0.19 \pm 0.02$ , by simultaneously extracting the blueshift of the first satellite feature as well as the relative intensities of the replica bands to the main band which place tight constraints on theoretical models. This work not only demonstrates that replica bands in FeSe/SrTiO<sub>3</sub> arise from intrinsic electron-phonon coupling, but also suggests a new generalized methodology for extracting more quantitative information about electron-phonon coupling constants in quantum materials through comparisons to theory.

Monolayer FeSe films were grown by MBE on undoped SrTiO<sub>3</sub> substrates and measured immediately by *in situ* ARPES (He-I photons,  $h\nu = 21.2$  eV) as well as *in situ* resistivity measurements (Fig. S1). Having verified their quality and superconducting properties, samples were then capped with  $\approx 100$  nm amorphous Se for transport to the Advanced Light Source MAESTRO beamline (7.0.2) in a sealed, inert environment. Films were then decapped at the end station at 420°C, in a vacuum better than  $5 \times 10^{-10}$  Torr immediately prior to ARPES measurements. ARPES measurements were then performed at 15 K at photon energies ranging between 21–75 eV, with a total energy resolution of 10–20 meV (depending on the incident photon energy).

In Fig. 1 we present ARPES measurements of monolayer FeSe/SrTiO<sub>3</sub> after decapping, taken at  $h\nu = 24$  eV with *p*-polarized light. Consistent with previous reports, the Fermi surface is comprised of nearly degenerate elliptical electron pockets at *M* which arise from the glide-mirror symmetry of the iron-selenium plane [15]. Because of the matrix element effects, the electron pocket at *M*<sub>1</sub> appears with lobes of increased intensity in a threefold pattern about the pocket. In Figs. 1(b) and 1(c), we show raw and second-derivative spectra taken along the  $\Gamma - M$  direction as indicated by the blue line in Fig. 1(a). The main band closest to  $E_F$ , which we denote as  $\gamma$ , exhibits a well-defined gap and backbending at 15 K, indicative of the expected superconductivity. The first replica band, ( $\gamma'$ , red) is visible in the raw ARPES spectra 98 meV below the main band. Two additional, weaker features are also visible in the

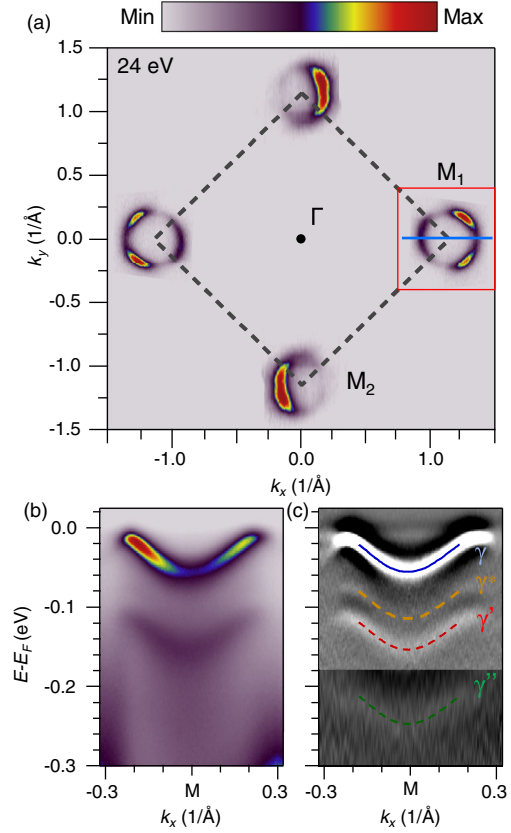


FIG. 1. Fermi surface and replica band topology in single-layer FeSe/SrTiO<sub>3</sub>. (a) Fermi surface map of single-layer FeSe/SrTiO<sub>3</sub> taken with *p*-polarized light at  $h\nu = 24$  eV. (b) High-statistics spectra along the cut shown at *M*<sub>1</sub> (blue). (c) Second-derivative of the spectra in (b). An additional 60 meV replica (labeled  $\gamma^*$  in the figure) is clearly visible, as well as a second-order replica (labeled  $\gamma''$ ) after saturating the color scale over the higher binding energy region.

second-derivative spectra shown in Fig. 1(c), including a faint replica at  $\approx 60$  meV (denoted as  $\gamma^*$ , shown in orange), and also an additional replica band separated by 192 meV from the main band ( $\gamma''$ , denoted in green). Their characteristic energies associate them with two distinct Fuchs-Kliwer (FK) phonons of the SrTiO<sub>3</sub> substrate, which arise from out-of-plane vibration modes of the oppositely charged Ti and O ions [16];  $\gamma^*$  corresponds to FK<sub>2</sub>, and  $\gamma'$  and  $\gamma''$  are the first and second-order satellites from FK<sub>1</sub> [17].

If the replica bands indeed arise from extrinsic final-state energy losses, as suggested in Ref. [13], then it is predicted that the ratio of the intensity of the first replica band,  $\gamma'$ , relative to the intensity of the main band,  $\gamma$ ,  $I_{\gamma'}/I_{\gamma}$ , should depend strongly on the kinetic energy and direction of the outgoing photoelectron. Conversely, if the replica bands arise from electron-phonon coupling in the initial state, they should be intrinsic features of the single-particle spectral function and hence, the intensity ratio  $I_{\gamma'}/I_{\gamma}$  should be insensitive to the photoelectron kinetic energy. In Fig. 2(a),

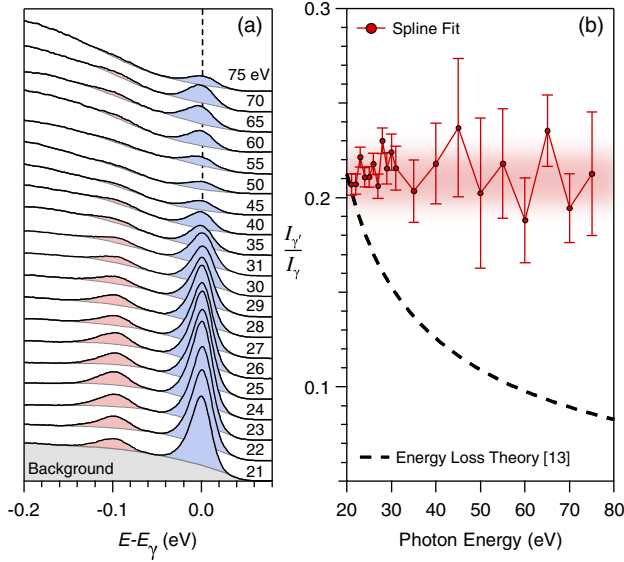


FIG. 2. Photon energy dependence of the replica band intensity. (a) Integrated EDCs collected from  $h\nu = 21$  to 75 eV. Grey lines indicate the spline background, while blue and red shaded regions indicate the integrated signal of the  $\gamma$  and  $\gamma'$  bands, respectively. (b) Relative intensity of  $\gamma'$  to  $\gamma$  as a function of incident photon energy (red markers) compared to the theoretical prediction for a photoelectron loss effect from Ref. [13] (black dashed line).

we plot energy distribution curves (EDCs) around  $M$  between  $21 \text{ eV} < h\nu < 75 \text{ eV}$  (corresponding to photoelectron kinetic energies between  $\approx 17$  to 71 eV). To improve statistics, the EDCs have been generated by integrating over the entire band, offsetting each individual EDC by the peak position of the main band  $\epsilon_k$  (Fig. S2), then fitted to a smooth spline background with the integrated weight of the main band peak ( $I_{\gamma}$ ) and replica band peak ( $I_{\gamma'}$ ) shown after subtraction in Fig. S3. In Fig. 2(b), we plot the ratio of  $I_{\gamma'}/I_{\gamma}$  as a function of photon energy, which is clearly independent of photon energy, with an extracted value of  $I_{\gamma'}/I_{\gamma} = 0.21 \pm 0.02$ , together with a comparison of the prediction for the extrinsic photoelectron energy loss scenario, where a  $\approx 60\%$  reduction in  $I_{\gamma'}/I_{\gamma}$  would have been expected. This is despite the fact that the overall absolute intensity of both  $I_{\gamma}$  and  $I_{\gamma'}$  drops by a factor of 10 in going to higher photon energies (hence the larger error bars for  $h\nu > 40 \text{ eV}$ ), thus definitively ruling out extrinsic photoelectron loss effects as the origin of the replica band in FeSe/SrTiO<sub>3</sub>. We have confirmed that this behavior is robust against details of the fitting procedure, for example, whether a single EDC at  $M$  is used as opposed to band-averaged spectra, or whether a Shirley background is used in place of a spline fit.

Performing this extensive photon energy dependence study provides the opportunity to extract more detailed information about the electron-phonon coupling than had previously been possible. For one, this analysis allows us to

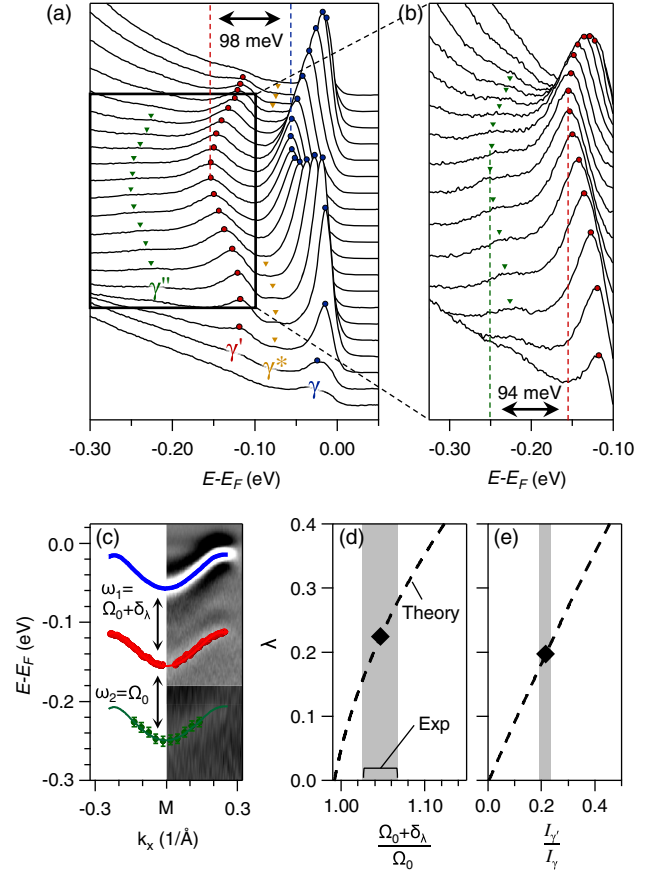


FIG. 3. Observation of second-order replica bands in single-layer FeSe/SrTiO<sub>3</sub>. (a),(b) EDCs across the spectra at  $M$  shown as a waterfall plot. Blue, red, yellow, and green markers track the main band ( $\gamma$ ), 98 meV replica ( $\gamma'$ ), and 60 meV replica ( $\gamma^*$ ), and 190 meV second order replica ( $\gamma''$ ), respectively. (c) Band positions based on fits to the EDC peak positions. (d),(e) Determination of the electron-phonon coupling constant  $\lambda$  based on the  $\gamma'$  blueshift (d) and replica band intensity (e). Theoretical behavior based on Ref. [20]. Grey regions indicate the experimental uncertainty.

reliably determine the absolute intensity of  $I_{\gamma'}/I_{\gamma} = 0.21 \pm 0.02$ . Furthermore, we are now able to identify an optimal photon energy,  $h\nu = 24 \text{ eV}$  with  $p$  polarization where the intensity of features is strongest, so as to enable a more detailed, quantitative line shape analysis of the spectral function and replica bands. In Figs. 3(a) and 3(b), we show a series of EDCs around  $M$  at 24 eV, with the band positions for  $\gamma$ ,  $\gamma^*$ ,  $\gamma'$ , and  $\gamma''$  indicated by markers. This data allows us to accurately determine the separation between  $\gamma$  and  $\gamma'$  as  $\omega_1 = 98 \pm 1 \text{ meV}$ , as well as the separation between the first and second replicas,  $\gamma'$  and  $\gamma''$ ,  $\omega_2 = 94 \pm 2 \text{ meV}$ , 4 meV less than  $\omega_1$ . These values for each replica feature, along with estimates of the relative band intensity based on fits to the background-subtracted EDCs (Fig. S6), are shown in Table I. The energy of the FK<sub>1</sub> phonon in the undoped SrTiO<sub>3</sub> substrate has previously been determined to be 94 meV [10,18],

TABLE I. Replica band energy offsets and relative intensities for  $\gamma^*$ ,  $\gamma'$ , and  $\gamma''$  based on fits to the EDC peak positions [Fig. 3(c)] and line shape (Fig. S6).

Band	Energy offset (meV)	Intensity ( $I_{\gamma^n}/I_\gamma$ )
$\gamma$	0	1.0
$\gamma^*$	$-59 \pm 2$	$0.02 \pm 0.01$
$\gamma'$	$-98 \pm 1$	$0.21 \pm 0.02$
$\gamma''$	$-192 \pm 2$	$0.04 \pm 0.025$

although this value is highly doping dependent [19]. Therefore, the separation between  $\gamma$  and  $\gamma'$  is blueshifted by  $\delta_\lambda = 4$  meV, relative to the bare  $\text{FK}_1$  phonon energy, as shown in Fig. 3(c). This is in contrast to the separation between  $\gamma'$  and  $\gamma''$ , which closely matches  $\Omega_{\text{FK}_1}$  to within experimental error ( $94 \pm 2$  meV).

Such a blueshift of the first-order replica (and corresponding lack of a shift for the second-order replica), has been discussed theoretically in various systems [8,20–23], but to our knowledge, this is the first instance where this behavior has been clearly identified experimentally. As has been discussed theoretically, reliably extracting both the blueshift,  $\delta_\lambda$  (or alternatively  $\omega_1/\omega_2$ ), as well as the intensity ratio between the main and first replica bands,  $I_{\gamma'}/I_\gamma$ , allows us to more accurately infer the strength of the electron-phonon coupling, which we describe via the dimensionless parameter  $\lambda$  as the Fermi surface average of the momentum-dependent coupling constant  $g(\mathbf{q}) = g_0 e^{-|q|/q_0}$  used in theoretical models [24–27]. This is of particular importance to the FeSe/SrTiO<sub>3</sub> system, since the possible enhancement of  $T_c$  due to coupling to interfacial substrate phonons has been shown to vary strongly as a function of  $\lambda$  in certain models [20–22].

Performing accurate and realistic calculations of electron-phonon interactions in quantum materials remains a long-standing theoretical challenge. By simultaneously comparing two independently extracted experimental quantities that are both related to  $\lambda$ ,  $I_{\gamma'}/I_\gamma$ , and  $\omega_1/\omega_2$ , we can tightly constrain existing theoretical calculations of electron-phonon coupling in FeSe/SrTiO<sub>3</sub>. For previous work based on either single-band or multiband Migdal-Eliashberg calculations [21,22,27], we have found that it is not possible for a single value of  $\lambda$  in the calculations to simultaneously match both our experimentally determined blueshift ( $\omega_1/\omega_2 = 1.045 \pm 0.025$ ) as well as intensity ratio ( $I_{\gamma'}/I_\gamma = 0.21 \pm 0.02$ ). For instance, in Ref. [22], a theoretical value of  $\lambda \approx 0.2$  is needed to match the experimental blueshift,  $\omega_1/\omega_2$ , whereas a value of  $\lambda \approx 1.05$  is needed to match the experimental intensity ratio, as shown in Fig. S4 (we note that  $\lambda \approx 4.17\lambda_m$  for forward scattering of  $q_0 = 0.1/a$  [22,26]). Alternatively, we find that prior calculations by Li *et al.* based on sign-problem-free quantum Monte Carlo simulations of FeSe/SrTiO<sub>3</sub> in the presence of strong forward scattering yield values of

$I_{\gamma'}/I_\gamma$  and  $\omega_1/\omega_2$  that agree with our experiments for a single value of  $\lambda = 0.19 \pm 0.02$  [20]. The theoretical results in this limit of small momentum transfer for both  $I_{\gamma'}/I_\gamma$  and  $\delta_\lambda$  are reproduced as dashed lines in Figs. 3(d) and 3(e), together with our experimentally determined values for both quantities (shown as shaded bars, which denote our experimental uncertainty).

For a value of  $\lambda = 0.19$ , calculations by Li *et al.* would suggest an interfacial enhancement of  $\Delta$  of  $\approx 11\%$  [20]. While considerable, this cannot entirely account for a gap closing temperature of 60–70 K compared to bulk electron-doped FeSe compounds ( $T_c \approx 40$  K), indicating that other effects might be at play. Combined *in situ* resistivity and ARPES measurements have revealed the presence of a pseudogap above 40 K in monolayer FeSe/SrTiO<sub>3</sub> [28]. A similar pseudogap phase has also been reported in the highly two-dimensional bulk intercalated compound (TBA<sup>+</sup>)FeSe up to 60 K ( $c = 15.5$  Å;  $\rho_c/\rho_{ab} \approx 10^5$ ) [29], which is absent any interfacial effects, suggesting that enhanced pre-formed pairing in monolayer FeSe/SrTiO<sub>3</sub> and (TBA<sup>+</sup>)FeSe could arise predominantly from the enhanced two dimensionality of the electronic structure. This could also explain why the reported gap closing temperatures in monolayer FeSe/SrTiO<sub>3</sub> are universally high, even when the replica bands are fairly weak or not observed [30–34]. Nevertheless, given that the observed replica bands arise from intrinsic interfacial electron-phonon coupling, our result suggests that engineering alternative interface systems with stronger  $\lambda$  may offer a means by which to achieve a more substantial enhancement in monolayer superconducting films.

In addition to the blueshift and intensity ratios, a detailed analysis of the spectral function also reveals evidence for electron-phonon coupling in the lifetime broadening of the first replica band,  $\Gamma_{\gamma'}$  relative to that of the main band,  $\Gamma_\gamma$  (the second replica,  $\gamma''$ , is too weak to allow a reliable analysis of its line shape). In Fig. 4(a), we show the extracted spectral function after fitting to the backgrounds used in Fig. 2 (as before, our conclusions here are independent of the specific background that is employed, Fig. S5). The expected sharpening of the main band peak,  $\Gamma_\gamma$ , as it approaches  $E_F$  can be clearly observed in Fig. 4(b), where we plot  $\Gamma$  as a function of binding energy  $E_B$ . Likewise, the scattering rate of the first replica band,  $\Gamma_{\gamma'}$ , exhibits similar behavior, but with the minimum value of  $\Gamma_{\gamma'}$  (at  $k_F$ ) approximately equal to the maximum value of  $\Gamma_\gamma$  (taken at the band bottom,  $M$ ), as would be expected if both features naturally arise from a single, intrinsic spectral function. For comparison, we also plot the simulated linewidth of the first replica,  $\Gamma_{\gamma'}$  in the extrinsic photoelectron loss scenario, where the width would correspond to that of the main band  $\gamma$  convoluted with the lifetime of the  $\text{FK}_1$  phonon,  $\Gamma_{\text{FK}_1}$  [19]. As can be seen in Fig. 4(b), the experimentally determined value of  $\Gamma_{\gamma'}$  is substantially larger than would be expected in a



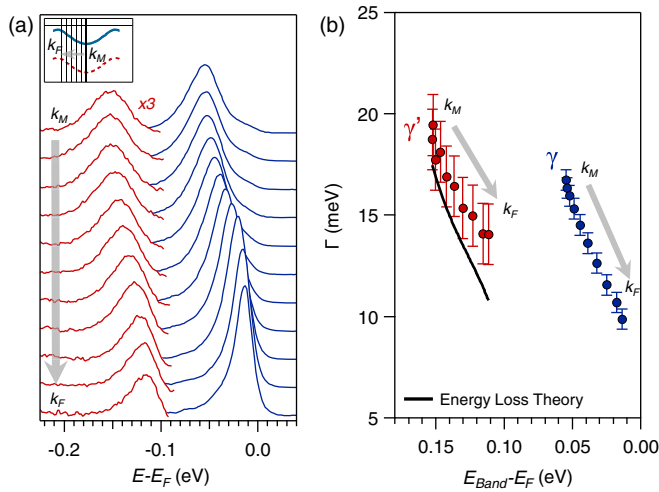


FIG. 4. Quasiparticle lifetime broadening in the replica band. (a) Background-subtracted EDCs spanning the electron pocket dispersion, from the band bottom ( $k_M$ ) to  $k_F$ , for data taken at  $h\nu = 24$  eV. The  $\gamma'$  feature has been multiplied by 3 for visual clarity. (b) Quasiparticle lifetimes based on spectral function fits for  $\gamma$  (blue) and  $\gamma'$  (red). The solid black line indicates the anticipated replica band behavior under the extrinsic photoelectron energy loss scenario.

photoelectron loss scenario, once again pointing towards its intrinsic character.

In summary, we have performed an extensive quantitative analysis of replica bands in the ARPES line shape of single-layer FeSe/SrTiO<sub>3</sub>, which allows us to reliably extract both the blueshift of the first replica band,  $\delta_\lambda$ , and the intensity ratio  $I_{\gamma'}/I_\gamma$  between the replica and main bands. A comparison with theoretical calculations in the limit of strong forward scattering allows us to accurately determine the strength of the coupling between electrons in the FeSe layer and Fuchs-Kliwer phonons in the SrTiO<sub>3</sub> substrate as  $\lambda = 0.19 \pm 0.02$ , suggesting that the enhancement of the superconducting gap from interfacial coupling is approximately 11%. This implies that interfacial coupling alone may not account for the enhanced gap closing temperature reported by ARPES. Our reliable quantification of the replica band parameters provides important constraints for theoretical studies of the forward-scattering electron-phonon interaction in the FeSe/SrTiO<sub>3</sub> system. More generally, our analysis suggests a new methodology for comparisons with theory and quantitatively extracting electron-phonon coupling constants.

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